

The Waterloo Institute for Nanotechnology

Presents

MBE Growth of III-Nitrides

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MBE growth of group III-Nitrides can be done in two ways depending on the source of active nitrogen. One option is to use ammonia as the active species, so called NH₃-MBE. The other option is to use a plasma source – so called PA-MBE. In this talk I will concentrate on the latter, since this is radically different to the normal III-V growth.



Friday, June 6th, 2014
10:00-11:00am
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